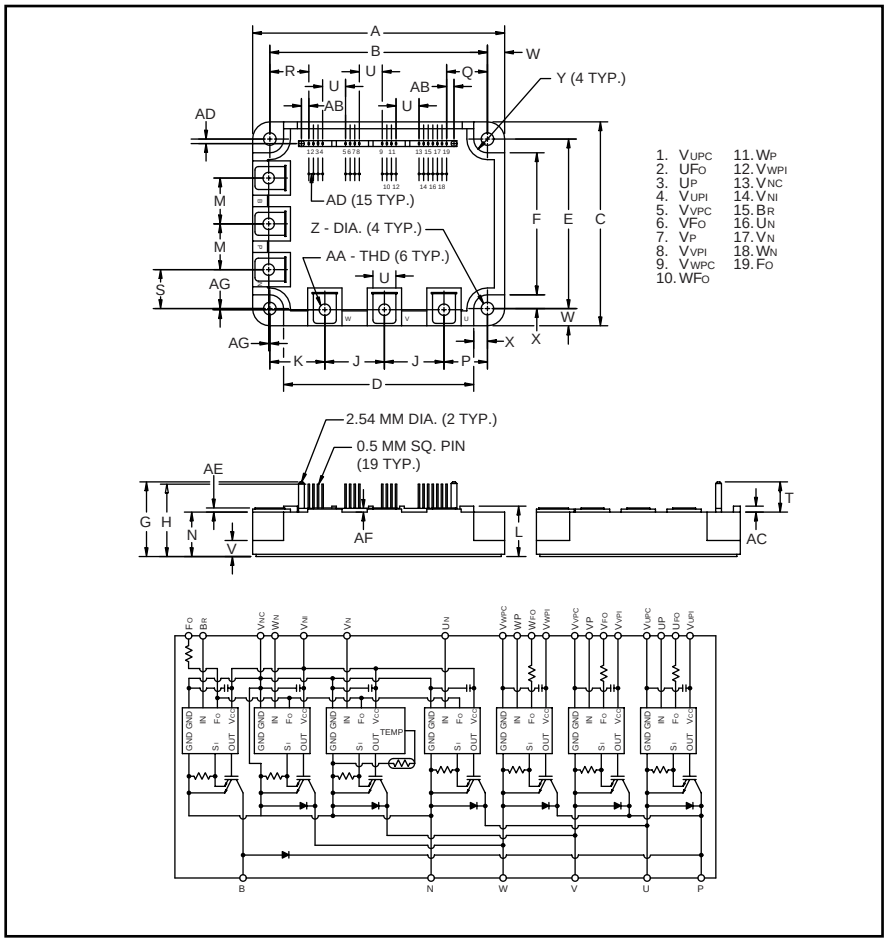
MITSUBISHI INTELLIGENT POWER MODULES

PM150RSA060

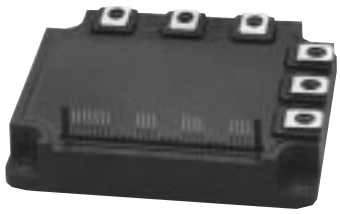
FLAT-BASE TYPE
INSULATED PACKAGE



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.33±0.04	110.0±1.0
B	3.74±0.02	95.0±0.5
C	3.50±0.04	89.0±1.0
D	3.27	83.0
E	2.91±0.02	74.0±0.5
F	2.44	62.0
G	1.28	32.6
H	1.24	31.6
J	1.02	26.0
K	0.94	24.0
L	0.87 +0.06/-0.0	22.0 +1.5/-0.0
M	0.79	20.0
N	0.76	19.4
P	0.75	19.0
Q	0.708	17.98
R	0.670	17.02

Dimensions	Inches	Millimeters
S	0.67	17.0
T	0.52	13.2
U	0.39	10.0
V	0.276	7.0
W	0.30	7.5
X	0.24	6.0
Y	0.24 Rad.	Rad. 6.0
Z	0.22 Dia.	Dia. 5.5
AA	Metric M5	M5
AB	0.127	3.22
AC	0.10	2.6
AD	0.08	2.0
AE	0.07	1.8
AF	0.06	1.6
AG	0.02±0.01	0.5±0.3



Description:
Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:
- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Current
  - – Over Temperature
  - – Under Voltage

Applications:
- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:
Example: Select the complete part number from the table below -i.e. PM150RSA060 is a 600V, 150 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	150	60

MITSUBISHI ELECTRIC

Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

	Symbol	Ratings	Units
Power Device Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Case Operating Temperature	T_C	-20 to 100	°C
Mounting Torque, M5 Mounting Screws	—	1.47~1.96	N · m
Mounting Torque, M5 Main Terminal Screw	—	1.47~1.96	N · m
Module Weight (Typical)	—	550	Grams
Supply Voltage Protected by OC and SC (V_D = 13.5 - 16.5V, Inverter Part, T_j = 125°C)	$V_{CC(prot.)}$	400	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Vrms

Control Sector

Supply Voltage (Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N · V_N · W_N · B_r-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (U_{FO}-V_{UPC}, V_{FO}-V_{VPC}, W_{FO}-V_{WPC}, FO-V_{NC})	V_{FO}	20	Volts
Fault Output Current (Sink Current at U_{FO}, V_{FO}, W_{FO} and F_O Terminal)	I_{FO}	20	mA

IGBT Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current, (T_C=25°C)	I_C	150	Amperes
Peak Collector Current, (T_C=25°C)	I_{CP}	300	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	450	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	500	Volts
Collector Dissipation	P_C	500	Watts

Brake Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current, (T_C=25°C)	I_C	50	Amperes
Peak Collector Current, (T_C=25°C)	I_{CP}	100	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	450	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	500	Volts
Collector Dissipation	P_C	312	Watts
Diode Forward Current	I_F	50	Amperes
Diode DC Reverse Voltage	$V_{R(DC)}$	600	Volts

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Over Current Trip Level Inverter Part	OC	-20°C ≤ T ≤ 125°C, V_D=15V	210	300	—	Amperes
Over Current Trip Level Brake Part			65	88	—	Amperes
Short Circuit Trip Level Inverter Part	SC	-20°C ≤ T ≤ 125°C, V_D=15V	—	420	—	Amperes
Short Circuit Trip Level Brake Part			—	132	—	Amperes
Over Current Delay Time	$t_{off(OC)}$	V_D = 15V	—	10	—	µs
Over Temperature Protection	OT	Trip Level	111	118	125	°C
	OT_r	Reset Level	—	100	—	°C
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
	UV_r	Reset Level	—	12.5	—	Volts
Supply Voltage	V_D	Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC}	13.5	15	16.5	Volts
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	—	52	72	mA
		V_D = 15V, V_{CIN} = 15V, V_{XP1}-V_{XPC}	—	13	18	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied between	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, $U_N \cdot V_N \cdot W_N \cdot B_r$-$V_{NC}$	1.7	2.0	2.3	Volts
PWM Input Frequency	f_{PWM}	3-ϕ Sinusoidal	—	15	20	kHz
Fault Output Current	$I_{FO(H)}$	V_D = 15V, V_{FO} = 15V	—	—	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{FO} = 15V	—	10	15	mA
Minimum Fault Output Pulse Width	t_{FO}	V_D = 15V	1.0	1.8	—	ms
Brake Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 50A, T_j = 25°C	—	2.7	3.5	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 50A, T_j = 125°C	—	2.5	3.4	Volts
Diode Forward Voltage	V_{FM}	I_F = 50A, V_D = 15V, V_{CIN} = 15V	—	1.7	2.5	Volts
Collector Cutoff Current	I_{CES}	V_{CE} = V_{CES}, T_j = 25°C	—	—	1	mA
		V_{CE} = V_{CES}, T_j = 125°C	—	—	10	mA

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, T_j = 25°C	—	—	1	mA
		$V_{CE} = V_{CES}$, T_j = 125°C	—	—	10	mA
Diode Forward Voltage	V_{EC}	$-I_C$ = 150A, V_D = 15V, V_{CIN} = 15V	—	2.2	3.3	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 150A, T_j = 25°C	—	1.8	2.7	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 150A, T_j = 125°C	—	1.75	2.63	Volts
Inductive Load Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 ↔ 15V V_{CC} = 300V, I_C = 150A T_j = 125°C	0.4	0.8	2.0	µs
	t_{rr}		—	0.15	0.3	µs
	$t_{C(on)}$		—	0.4	1.0	µs
	t_{off}		—	2.0	2.9	µs
	$t_{C(off)}$		—	0.6	1.2	µs

Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each Inverter IGBT	—	—	0.25	°C/Watt
	$R_{th(j-c)F}$	Each Inverter FWDi	—	—	0.47	°C/Watt
	$R_{th(c-f)Q}$	Each Brake IGBT	—	—	0.4	°C/Watt
	$R_{th(c-f)F}$	Each Brake FWDi	—	—	1.0	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.027	°C/Watt

Recommended Conditions for Use

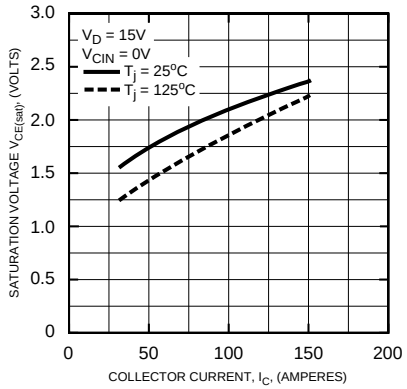
Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	0 ~ 400	Volts
	V_D	Applied between V_{UP1}-V_{UPC}, V_{N1}-V_{NC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}	15 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P, V_P, W_P, U_N, V_N, W_N, B_r	0 ~ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$		4.0 ~ V_D	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	5 ~ 20	kHz
Minimum Dead Time	t_{dead}	Input Signal	≥ 2.5	µs

PM150RSA060

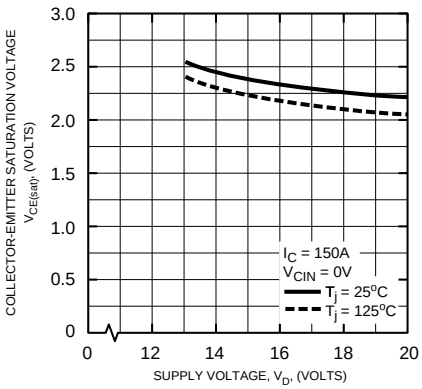
FLAT-BASE TYPE
INSULATED PACKAGE

Inverter Part

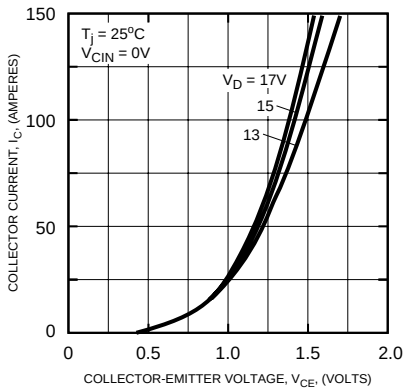
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



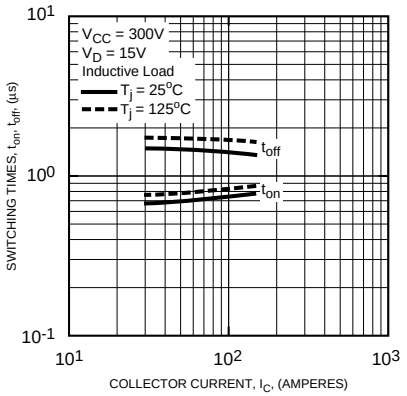
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



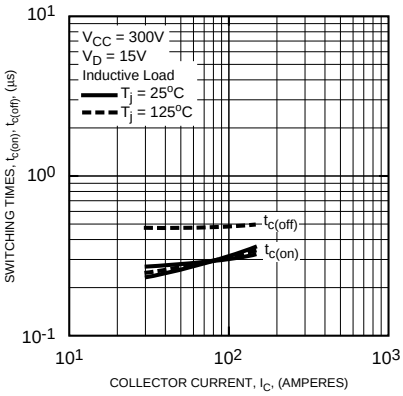
OUTPUT CHARACTERISTICS (TYPICAL)



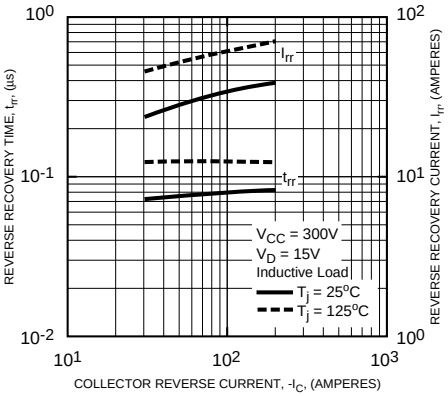
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



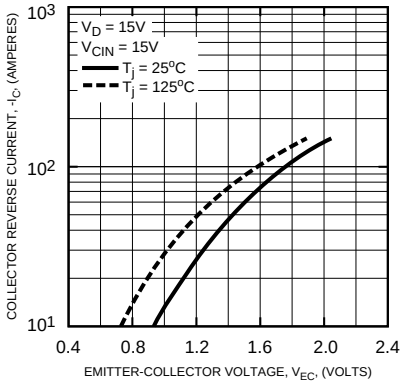
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



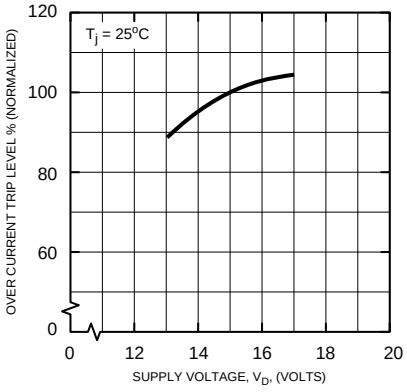
REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL)



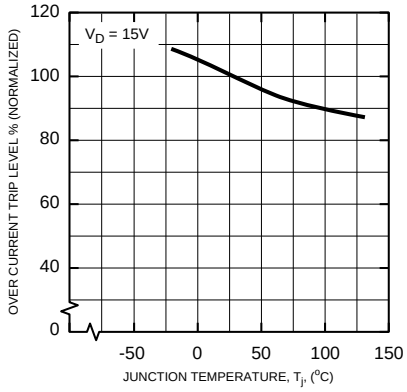
DIODE FORWARD CHARACTERISTICS



OVER CURRENT TRIP LEVEL VS. SUPPLY VOLTAGE (TYPICAL)



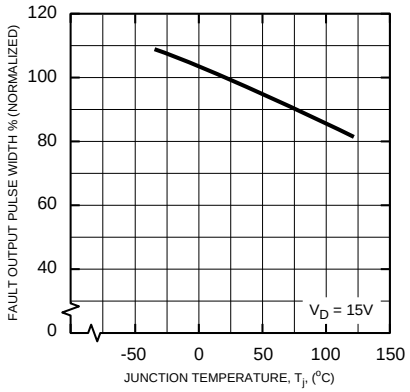
OVER CURRENT TRIP LEVEL VS. TEMPERATURE (TYPICAL)



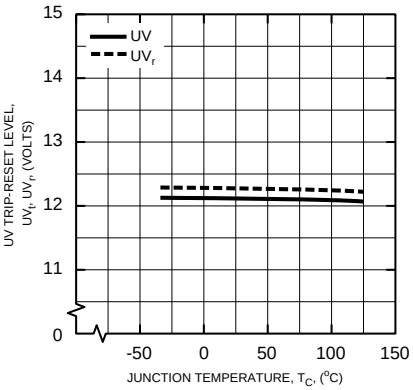
MITSUBISHI ELECTRIC

Inverter Part

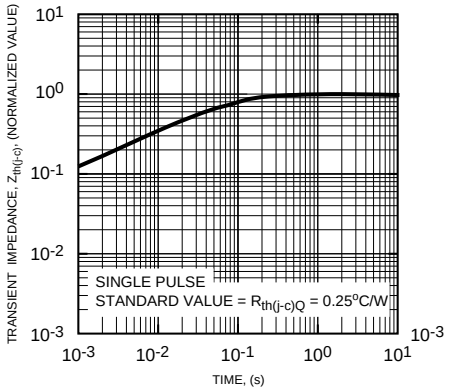
FAULT OUTPUT PULSE WIDTH VS. TEMPERATURE (TYPICAL)



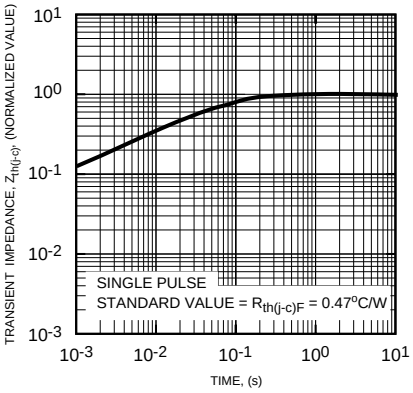
CONTROL SUPPLY VOLTAGE TRIP-RESET LEVEL TEMPERATURE DEPENDENCY (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each IGBT)

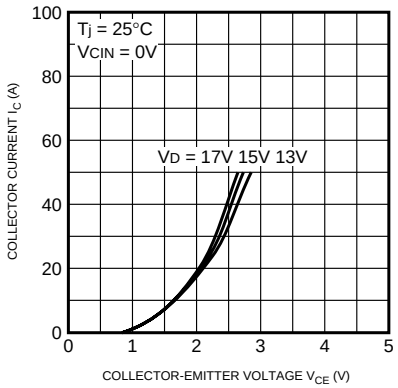


TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each FWDi)

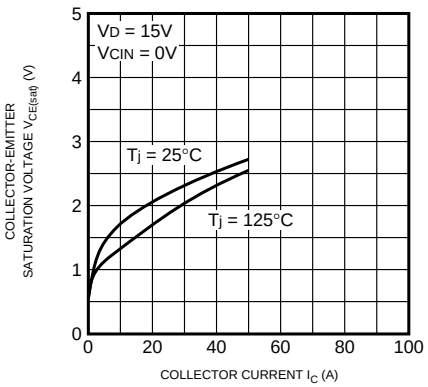


Brake Part

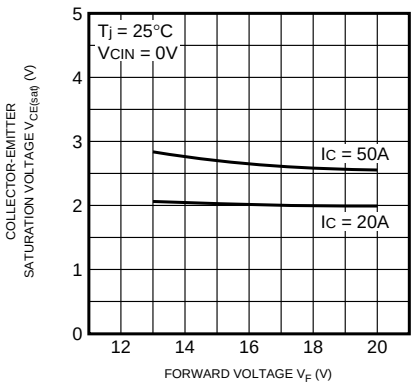
OUTPUT CHARACTERISTICS (TYPICAL)



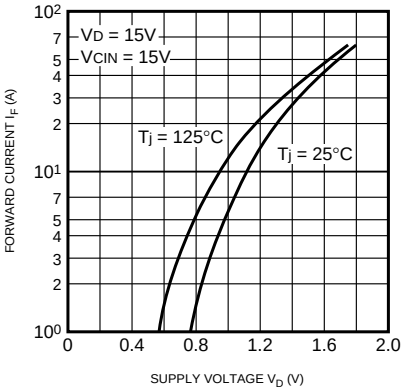
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



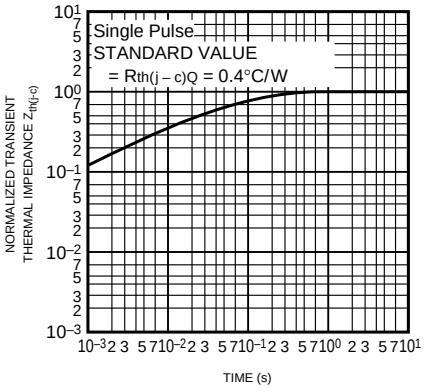
COLLECTOR-EMITTER SATURATION VOLTAGE VS. SUPPLY VOLTAGE (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT per 1 element)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (FWDi per 1 element)